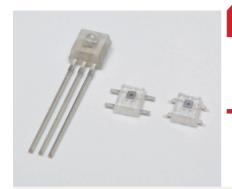
# HAMAMATSU

PHOTON IS OUR BUSINESS



# Low-voltage operation photo IC

S7610-10 S12558-01DT S12558-02DT

## High reliability photo IC operable at 2.2 V

The S7610-10, S12558-01DT and S12558-02DT are photo ICs comprised of a photodiode, amplifier, schmitt trigger circuit and output transistor, all integrated onto a single chip and molded with clear resin into a miniature package.

#### Features

- Low voltage operation (2.2 V)
- Open collector output
- L" level output at light input

#### Applications

- FSO (free space optics)
- Optical switch
- Rotary encoders, etc.

#### **→** Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	S7610-10	S12558-01DT S12558-02DT	Unit
Supply voltage	Vcc	-0.5 to +7		V
Output voltage	Vo	-0.5 to +7		
Low level output current	Io	8		
Power dissipation*1	Р	250		mW
Operating temperature	Topr	-30 to +85	-25 to +80	°C
Storage temperature	Tstg	-40 to +90	-30 to +85	°C
Soldering temperature	Tsol	*2	240 (once)*3	-

<sup>\*1:</sup> Power dissipation decreases at a rate of 3.3 mW/°C above Ta=25 °C .

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

#### **=** Electrical and optical characteristics (Ta=25 °C, Vcc=5 V, unless otherwise noted, light source: λp=890 nm LED)

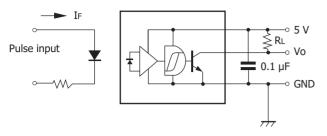
Param	neter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply voltage		Vcc		2.2	-	7.0	V
Low level output	voltage	Vol	IOL=4 mA, E=0.4 $\mu$ W/mm <sup>2</sup>	-	0.05	0.4	V
High level output	current	Іон	$E=0 \mu W/mm^2$ , $Vo=5 V$	-	-	10	μΑ
Current consump	tion	Icc		-	1.3	3	mA
H→L threshold	S7610-10	Ень	R <sub>I</sub> = 1.2 kΩ	-	0.10	0.25	μW/mm²
illuminance	S12558-01DT/-02DT	EHL	KL=1.2 K32	-	1.0	2.0	μνν/ιιιιι
Hysterisis		Hys	ELH/EHL	0.75	0.85	0.95	-
L→H propagation	n delay time	tplh	*4	-	4	15	μs
H→L propagation	n delay time	<b>t</b> PHL		-	1.5	10	μs
Peak sensitivity w	vavelength	λр		-	850	-	nm
Rise time		tr	*4	-	0.07	1	μs
Fall time		tf		-	0.03	1	μs

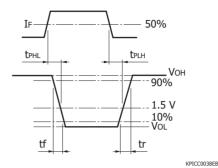
<sup>\*4:</sup> E<sub>0</sub>=0  $\mu$ W/mm², E<sub>1</sub>=0.4  $\mu$ W/mm², R<sub>L</sub>=1.2 kΩ, C<sub>L</sub>=10 pF (S7610-10) E<sub>0</sub>=0  $\mu$ W/mm², E<sub>1</sub>=4  $\mu$ W/mm², R<sub>L</sub>=1.2 kΩ, C<sub>L</sub>=10 pF (S12558-01DT/-02DT) C<sub>L</sub> includes probe capacitance.

<sup>\*2:</sup> See the recommended soldering conditions (P.8).

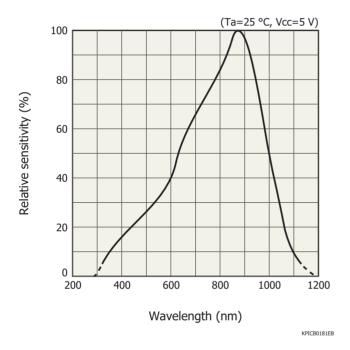
<sup>\*3:</sup> Reflow soldering, IPC/JEDEC J-STD-020 MSL 5a, see P.8

#### Response time measurement circuit

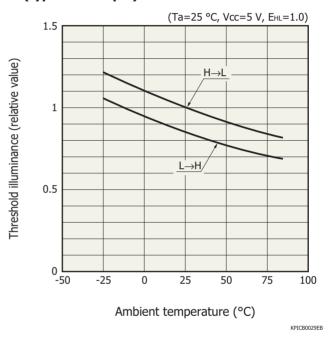




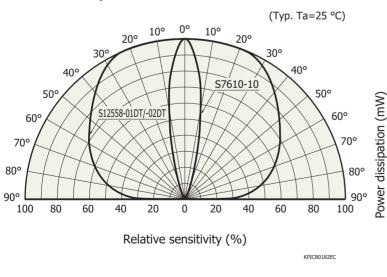
#### Spectral response (typical example)



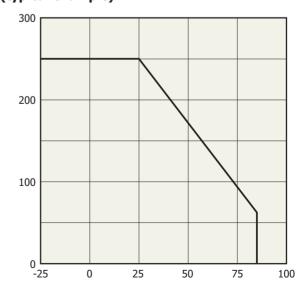
## Threshold illuminance vs. ambient temperature (typical example)



#### Directivity



## Power dissipation vs. ambient temperature (typical example)

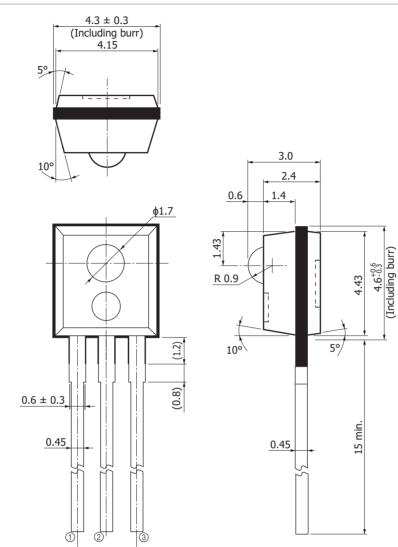


Ambient temperature (°C)

KPICB0049EA

## Dimensional outlines (unit: mm)

## S7610-10



① GND ② Vo ③ Vcc

 $2.54 \pm 0.5$ (Specified at lead root)

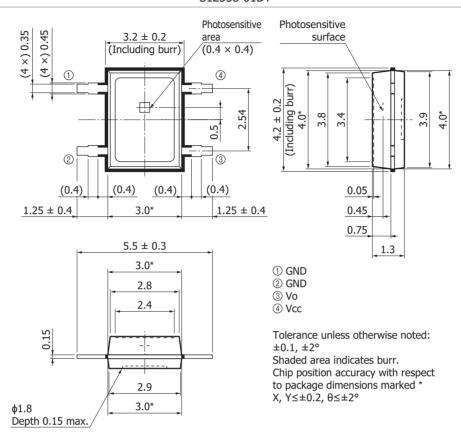
Tolerance unless otherwise noted:  $\pm 0.2$ ,  $\pm 2^{\circ}$ 

Shaded area indicates burr.

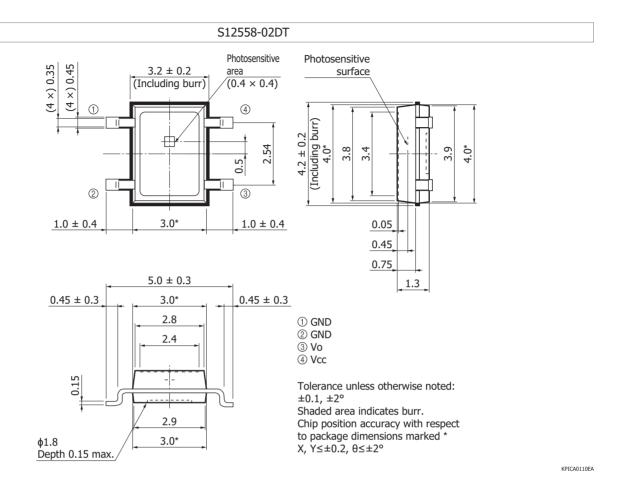
Values in parentheses are reference values.

KPICA0044ED

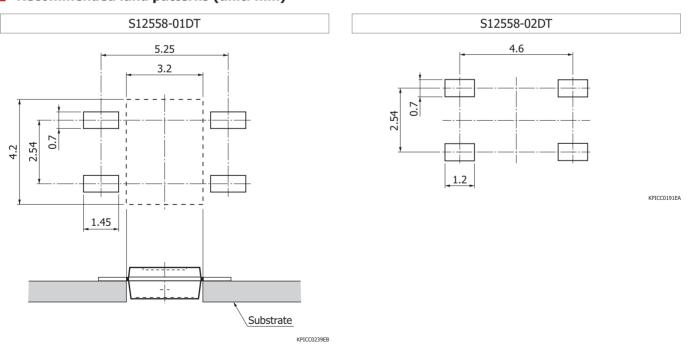
#### S12558-01DT



KPICA0093EA



#### Recommended land patterns (unit: mm)



## Standard packing specifications

S7610-10

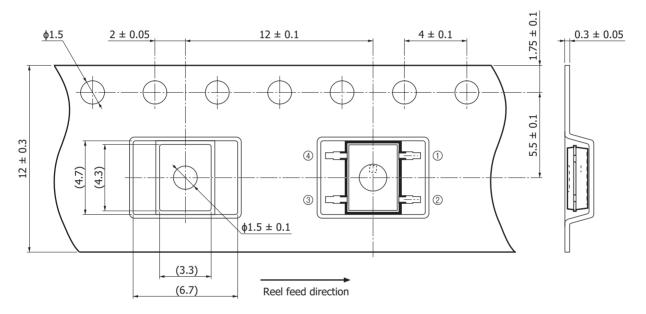
Packing typePolyethylene bag (antistatic type)500 pcs/bag

#### S12558-01DT

■ Reel (conforms to JEITA ET-7200)

Dimensions	Hub diameter	Tape width	Material	Electrostatic characteristics
254 mm	80 mm	12 mm	PS	Conductive

■ Embossed tape (unit: mm, material: PS, electrically conductive)





KPICC0240E

■ Packing quantity 1500 pcs/reel

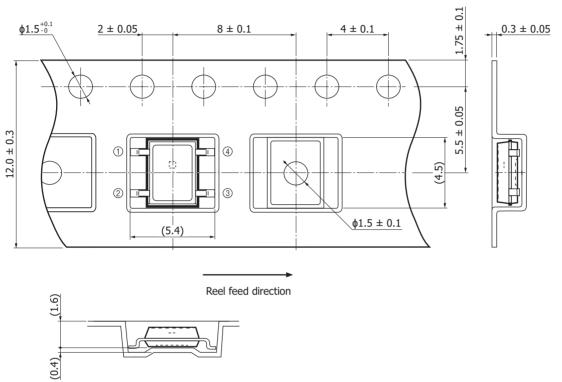
■ Packing type
Reel and desiccant in moisture-proof packaging (vacuum-sealed)

#### S12558-02DT

#### ■ Reel (conforms to JEITA ET-7200)

Dimensions	Hub diameter	Tape width	Material	Electrostatic characteristics
254 mm	80 mm	12 mm	PS	Conductive

■ Embossed tape (unit: mm, material: PS, electrically conductive)



KPICC0337EB

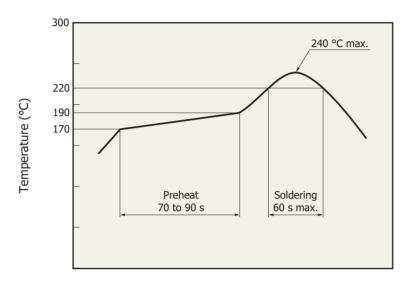
- Packing quantity 2000 pcs/reel
- Packing type
  Reel and desiccant in moisture-proof packaging (vacuum-sealed)

#### Recommended soldering conditions

S7610-10			
Parameter Specification		Remarks	
Solder temperature	260 °C max. (once, less than 3 s)	at least 2.5 mm away from lead roots	

Note: When setting the soldering conditions, check for any problems by testing out the soldering methods in advance.

#### S12558-01DT/-02DT



Time

KPICB0194EA

#### Note:

- The S12558-01DT/-02DT support lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 24 hours.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When setting the reflow soldering conditions, check for any problems by testing out the reflow soldering methods in advance.

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- · Notice
- · Metal, ceramic, plastic package products
- · Surface mount type products

Information described in this material is current as of April 2021.

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The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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